Nanosphere lithography with variable deposition angle for the production of one-directional transparent conductors.

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The production of high quality and cheap transparent electrodes is a fundamental step for a variety of optoelectronic devices. We present a method for the production of transparent conducting films optimised for electrical conduction in one direction. The deposition of a metal film through a perfectly aligned nanosphere-lithography mask at variable incidence angle gave origin to parallel nanowires with thin interconnections. This structure showed excellent conductivity in one direction and high optical transparency.

**1 Introduction** Optoelectronic devices such as OLEDs, flat displays, touch screens and photovoltaic cells usually need a transparent conductor (TC) as top electrode. Moreover, transparent conductors are used for frost-free windows, antistatic layers, transparent antennas and electromagnetic shields [1]. Commonly, tin-doped indium oxide, or ITO [2], is used. ITO has high transparency in the visible and near ultraviolet, and a high charge-carrier density providing sufficient electrical conductivity for most applications [3]. Disadvantages of ITO are the scarcity and costs of indium [4], the low mechanical flexibility [5], the degradation over time and its work function and roughness limiting the hole-injection efficiency [6,7] in semiconductors. Other transparent conducting oxides such as aluminium doped zinc oxide [8,9], fluorine doped tin oxide [10] as well as graphene, carbon nanotubes [11] and organic polymers like PEDOT:PSS [12] are alternative TC under investigation.

If wire grids are used as TC for semiconducting devices, the spacing between the wires must be lower than the diffusion length of the minority charge carriers [13,14], which ranges from 10–20 nm for organic solar cells [15], approximately 300 nm for amorphous silicon [16] and over 100 µm for thin-film crystalline silicon solar cells [17]. Several approaches were used for the production of nanostructured electrodes, e.g. the evaporation of metals on electrospun fibres [5] and the deposition of metals on a thin film gel cracked by desiccation [18,19]. Metallic films with ordered nanoholes produced by nanosphere lithography showed good electrical conductivity, but low optical transparency [20–23]. Highly symmetric structures cause additional optical absorption due to the interaction of light with surface plasmons, which can, both, reduce the overall transmission, but also enhance it for specific wavelength bands (extraordinary optical transmission) [24].

Wire-grid electrodes can be optimised for one-directional conductivity. A structure of aligned nanowires perpendicular to the side contacts leaves a higher portion of apertures for light transmission and reduces the symmetry. Transparent conductors with one-directional conductivity and excellent properties were produced by metal transfer from a PDMS stamp [6,25]. Even higher quality was achieved in a two-step process by deposition of copper mesoscale wires covered by silver nanowires (below 1 Ω/□ sheet resistance and over 90% optical transmission) [26].

Nanosphere lithography (NSL) was already used for the production of anisotropic metallic grids, which requires monocrystalline and oriented nanospheres masks [27,28].

Glass substrates under the crystalline areas of the polystyrene-nanospheres mask.
Here we present an alternative method based on the deposition at variable incidence angle, which benefits from a simpler geometry of the evaporation chamber. A metallic structure of thick parallel lines with thin interconnections was deposited, which lead to excellent sheet resistance below 3 Ω/□ and good transparency with an easy production method. Due to the geometry, the optical transmission is higher for light polarised perpendicularly to the lines, which can be exploited for particular applications absorbing or emitting polarised light (e.g. liquid crystal displays). Depending on the application, apertures in the 100–1000 nm range can be achieved.

2 Experimental methods

Nanostructured films of gold or silver were produced by nanosphere lithography and physical vapour deposition on glass substrates.

2.1 Nanosphere Lithography Monolayers of polystyrene (PS) nanospheres with 754 nm diameter were deposited on a clean distilled water surface with a specially bent pipette [29]. For a 500 cm² surface, 500 µL of a 5% w/v colloidal dispersion of nanospheres in water-ethanol mixture were used. The spheres spontaneously formed crystalline domains with hexagonal symmetry. Carefully inducing small waves on the surface helped rearranging and aligning the domains to form larger crystals (over 200 cm²). Introducing a tiny quantity of oil or grease on the water surface squeezed the spheres together until close packing was reached. The monolayer was deposited onto glass substrates by evaporation of the water (see Figure in the Abstract). The spheres were reduced to 2/3 of their size by reactive ion etching in an oxygen-argon plasma according to Akinoglu et al. [30] in a MiniFlecto RIE chamber from Plasma Technology. The orientation of the crystal was determined by diffraction of a 532 nm laser beam. The laser wavelength should be about 60-90% of the periodicity (i.e. original size of the spheres); therefore if the periodicity is lower than 450 nm or higher than 1 µm, the orientation of the mask shall be determined by microscopy.

2.2 Physical vapour deposition Metallic films were deposited onto the glass substrates through the NSL masks. The deposition was performed at variable incident angle by tilting the sample, so that oval apertures with different aspect ratio could be achieved as shadows of the spheres: the short axis remained equal to the sphere diameter, the long axis increased for higher angles. The samples were mounted in the deposition chamber such that the spheres rows were aligned with the long axes of the ovals. There is a critical deposition angle at which the long axis reaches the periodicity, i.e. the oval apertures percolate [31]. The critical angle can be determined by microscopy (AFM or SEM) or by electrical conductivity measurements (see Section 3). For this work, 60-70 nm of silver or gold were deposited on a 1-2 nm thick layer of titanium for better adhesion on the glass substrate. The evaporation was performed at a distance of 15 cm, a vacuum of 10⁻⁷ hPa and a deposition rate of 1 nm/min. The first part of the metal deposition (15-20 nm) was performed just below the critical angle (40° to the perpendicular) and originated a film with oval apertures. The incidence angle was then increased (60° to the perpendicular) to deposit thick lines parallel to the long axis of the oval apertures (150 nm width and 45-50 nm thickness), as visible in Fig. 1. The lines are responsible for the biggest amount of the electrical conductivity. The underlying film with holes provides interconnections that bypass defects in the lines. After metal deposition, the spheres were removed by sonication in toluene. The samples were annealed for 3 h in vacuum at 300°C for gold nanostructures or 120°C for silver nanostructures.

2.3 Characterisation Optical transmission was measured between 300 nm and 1100 nm with a Thermo Scientific Evolution Array UV-Vis-IR spectrometer and the average value in the visible spectrum was evaluated. For the sheet-resistance determination, silver electrodes were deposited at the sides of the sample perpendicularly to the lines. Four-point measurements were performed with a current of 0.1 A.

3 Results First, we analysed the properties of simple metallic films with oval apertures. A deposition at perpendicular angle (0°) produced a film with circular apertures, which had high conductivity but low transparency due to the small apertures and high symmetry of the structure (Fig. 2). Increasing the deposition angle elongates the apertures to ovals, which then percolated forming lines [31]. This reduced the symmetry and increased the aperture size for light transmission. As a consequence, we observed a strong increase in transparency with little losses in conductivity up to the critical angle at which the ovals percolate. In particular, we measured for a deposition angle of 40° unchanged electrical conductivity in the long-axis direction and 70% higher transparency. For higher angles, the structure consisted of lines, whereby single defects or damages were sufficient to block the electrical conductivity of whole lines, with a sudden drop in the conductivity.

Figure 1 SEM micrograph of silver lines on a film with oval apertures.
The superposition of thick lines on the film with oval apertures (Fig. 1) allowed combining the excellent optical and electrical properties of the lines and the bypassing of defects by the thin interconnections. This leads to a sheet resistance along the lines below 10 Ω/□ for silver films with 60% optical transmission and 5 Ω/□ for gold films with 70% transmission. Perpendicularly to the lines a sheet resistance of over 1000 Ω/□ was measured, which is in agreement with the results of Morfa et al [32]. We noticed that lattice defects interrupting the lines (e.g. due to spheres of wrong size or crystal lattice defects) usually create additional interconnections in the vicinity. In this way, the line defects are efficiently bypassed in spite of the very high sheet resistance perpendicularly to the lines. Despite the higher cost, gold films also have a transmission spectrum better fitting the visible and NIR spectrum of the sun (Fig. 3), which is convenient for most applications. The silver nanostructures have an extraordinary optical transmission peak at 325 nm, the gold nanostructures weaker peaks at 500 nm and 1100 nm. The EOT peaks can be shifted by changing the periodicity of the nanostructure, i.e. the sphere size of the lithographic mask. They are more pronounced for higher symmetry (low deposition angle), whereby an increase in symmetry reduces the overall transmission due to plasmonic absorption.